

BD136/138/140

Medium Power Linear and Switching Applications

• Complement to BD135, BD137 and BD139 respectively



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parar	neter	Value	Units
V _{CBO}	Collector-Base Voltage	: BD136	- 45	V
	C CI	: BD138	- 60	V
	DZSU DZSU	: BD140	- 80	V
V _{CEO}	Collector-Emitter Voltage	: BD136	- 45	V
		: BD138	- 60	V
		: BD140	- 80	V
V _{EBO}	Emitter-Base Voltage		- 5	V
I _C	Collector Current (DC)		- 1.5	А
I _{CP}	Collector Current (Pulse)		- 3.0	Α
I _B	Base Current		- 0.5	Α
P _C	Collector Dissipation (T _C =25°C)		12.5	W
P _C	Collector Dissipation (T _a =25°C)	9////	1.25	W
T _J	Junction Temperature		150	°C
T _{STG}	Storage Temperature	3.00	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage					931
	: BD136	$I_{C} = -30 \text{mA}, I_{B} = 0$	- 45			V
	: BD138		- 60	3.73		V
	: BD140	4 Martin 11-11-11	- 80	NU W	Dr.	V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -30V, I_{E} = 0$			- 0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 10	μΑ
h _{FE1}	* DC Current Gain	$V_{CE} = -2V, I_{C} = -5mA$	25			
h _{FF2}	- TID 170 M	$V_{CF} = -2V, I_{C} = -0.5A$	25			ĺ
h _{FE3}	FB 7 750.00	$V_{CE} = -2V, I_{C} = -150mA$	40		250	1
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = - 500mA, I _B = - 50mA			- 0.5	V
V _{BE} (on)	* Base-Emitter ON Voltage	$V_{CE} = -2V, I_{C} = -0.5A$			- 1	V

h_{FF} Classification

Classification	6	10	16
h _{FE3}	40 ~ 100	63 ~ 160	100 ~ 250

Typical Characteristics

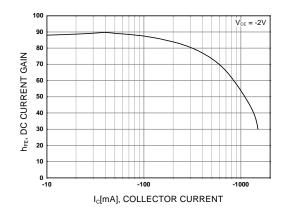


Figure 1. DC current Gain

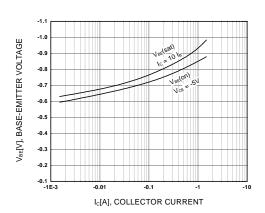


Figure 3. Base-Emitter Voltage

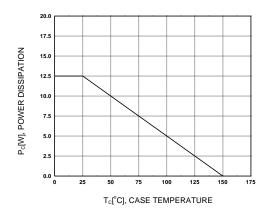


Figure 5. Power Derating

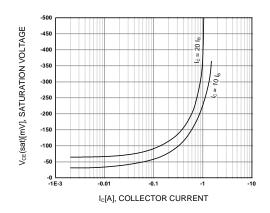


Figure 2. Collector-Emitter Saturation Voltage

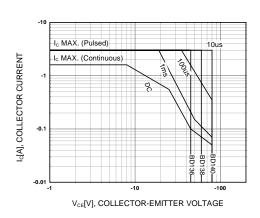
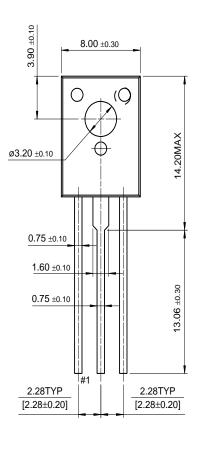


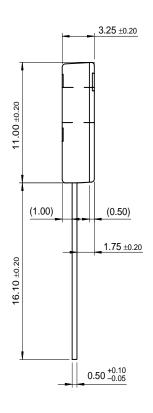
Figure 4. Safe Operating Area

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Package Demensions

TO-126







Dimensions in Millimeters

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